

#### **Description**

The AU1581P4-3 is a high power TVS, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive lines. The AU1581P4-3 complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. It is assembled into a 3-pin DFN2020-3 lead-free package. The leads are finished with NiPdAu. Each device will protect one line. The combination of small size, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multi media card interfaces.

#### **Features**

- Low leakage: nA level
- Operating voltage: 15V
- Ultra low clamping voltage
- One power line protects
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 300A (8/20µs)
- RoHS Compliant

### **Mechanical Characteristics**

Package: DFN2020-3

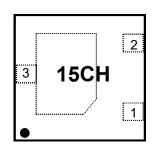
Case Material: "Green" Molding CompoundTerminal Connections: See Diagram Below

Marking Information: See Below

### **Applications**

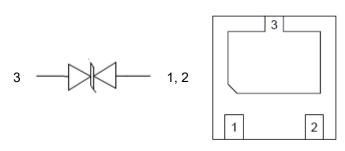
- Power Management
- Industrial Application
- Power Supply Protection
- Notebooks, desktops, and servers

### **Marking Information**



15CH:Deavice Marking Code

## **Dimensions and Pin Configuration**



Transparent top view

Circuit Diagram

Pin Schematic

## **Ordering Information**

Part Number	Packaging	Reel Size
AU1581P4-3	3000/Tape & Reel	7 inch



# Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise specified)

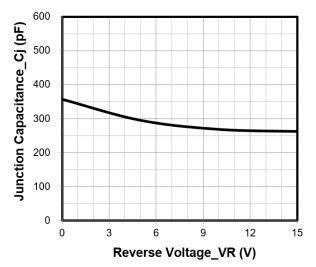
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	10,500	W
Peak Pulse Current (8/20µs)	IPP	300	Α
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±30 ±30	kV
Operating Temperature Range	TJ	−55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

# Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise specified)

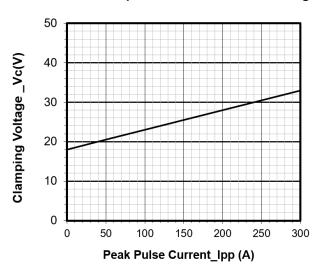
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			15	V	
Breakdown Voltage	VBR	16.5			V	IT = 1mA
Reverse Leakage Current	I <sub>R</sub>			1.0	μA	VRWM = 15V
Clamping Voltage	Vc			25	V	IPP = 50A (8 x 20µs pulse)
Clamping Voltage	Vc			35	V	IPP = 300A (8 x 20µs pulse)
Junction Capacitance	CJ			500	pF	VR = 0V, f = 1MHz



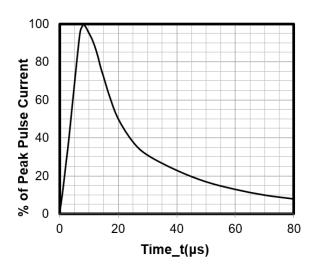
## Typical Performance Characteristics (T<sub>A</sub>=25°C unless otherwise Specified)



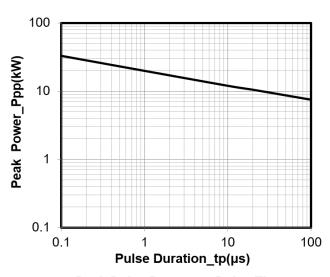
Junction Capacitance vs. Reverse Voltage



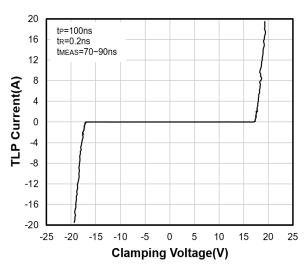
Clamping Voltage vs. Peak Pulse Current



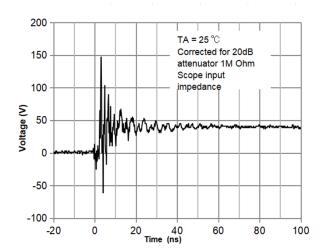
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



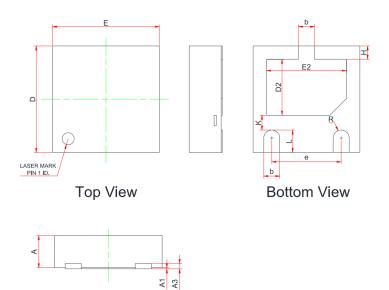
**TLP Curve** 



ESD Clamping Voltage 8 kV Contact per IEC61000-4-2



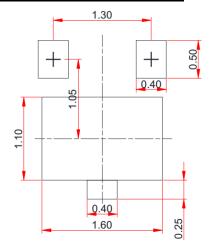
## **DFN2020-3 Package Outline Drawing**



	MILLIMETERS				
SYM	MIN	NOM	MAX		
Α	0.55	0.60	0.65		
A1	0.00	0.02	0.05		
A3	0.10REF.				
b	0.25		0.35		
D	1.90		2.10		
Е	1.90		2.10		
D2	0.95		1.15		
E2	1.40		1.60		
е	1.20		1.40		
Н	0.20		0.30		
K	0.20		0.40		
L	0.35		0.45		
R	0.13				

### **Suggested Land Pattern**

Side View



## **Contact Information**

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